

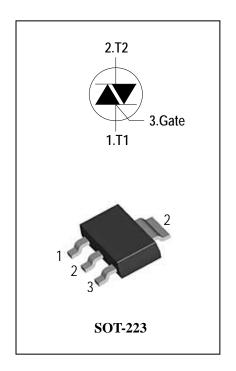
### 3Quadrants Triacs

### **General Description**

This device is suitable for low power AC switching application, phase control application such as fan speed and temperature modulation control, lighting control and static switching relay also designed for use in MPU interface, TTLlogic.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I<sub>T(RMS)</sub>= 1 A)
- ◆ High Commutation dv/dt≥500V/uS
- ◆ These Devices are Pb-Free and are RoHS Compliant



### **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Depotitive Deals Off Chate Valtage	T: - 25°C	ADS1C60W	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS1C80W	800	V
I <sub>T(RMS)</sub>	R.M.S On-State Current	T <sub>C</sub> = 85 °C		1	Α
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		10/11	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		1.12	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	tical rate of rise of on-state F = 120 Hz Tj = 125°C		50	A/µs
dl/dt	current	$I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$			
I <sub>GM</sub>	Peak Gate Current	tp = 20 μs Tj = 125°C		1	Α
P <sub>G(AV)</sub>	Average Gate Power Dissipation(Tj=125°C)			0.2	W
$P_{GM}$	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			1	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C



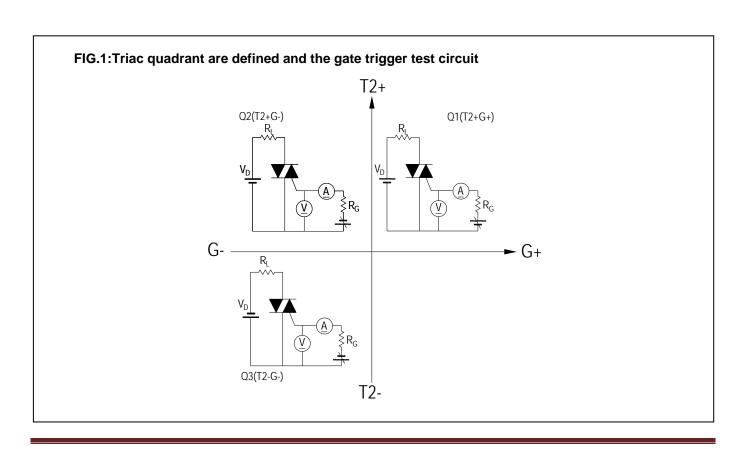


1/6 www.advsemi.com Feb,2013 -Rev.3.02



## **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		ADS1C60W/80W	Unit	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C	May	10	uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , Tj = 125°C	Max.	0.5	mA	
$V_{TM}$	Peak On-State Voltage		$I_{TM} = 1.4A$ , $t_p = 380 \ \mu s$	Max.	1.6	V	
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2	V	
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	\/ 40\/ B 000	Max.	1.5	V	
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	10	mA	
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	10	mA	
	Q1-Q3	Latabia a Commant			15		
ΙL	Q2	Latching Current	$I_G = 1.2 I_{GT}$	Max.	25	mA	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	500	V/µs	
(dV/dt)c	Rate of Change of Commutating  Current,		(dl/dt)c=-0.4A/ms Tj = 125°C	Min.	10	V/µs	
R <sub>th(j-c)</sub>	Junction to case (AC)			Max.	25	°C/W	
R <sub>th(j-a)</sub>	Junction to ambient(Copper surface under tab:S=5cm²)			Max.	60	°C/W	



# **ADV**

FIG.2: Maximum on-state power dissipation

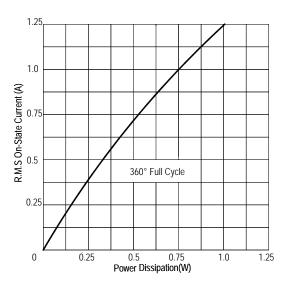


FIG.4: Gate trigger current VS Junction temperature

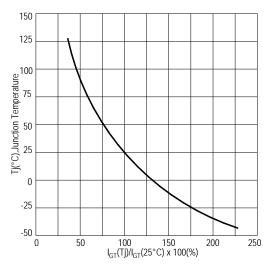


FIG.6: On-state characteristics(Max)

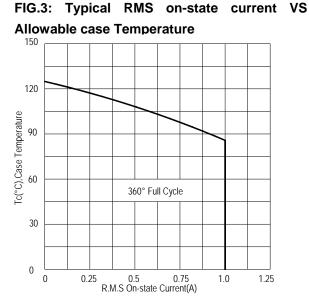
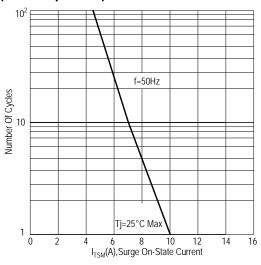


FIG.5: Rated surge on-state current (Non-Repetitive)



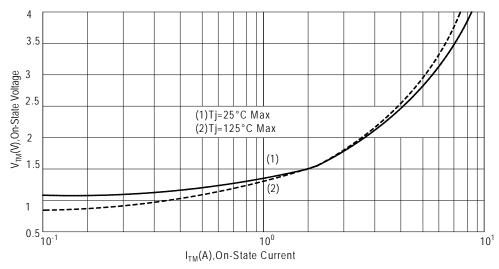




FIG.7:Holding current and Latching current VS Junction temperature

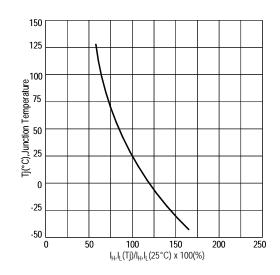
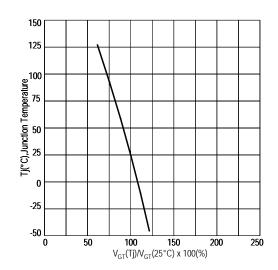
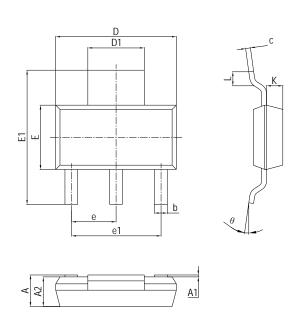


FIG.8: Gate trigger voltage VS Junction temperature



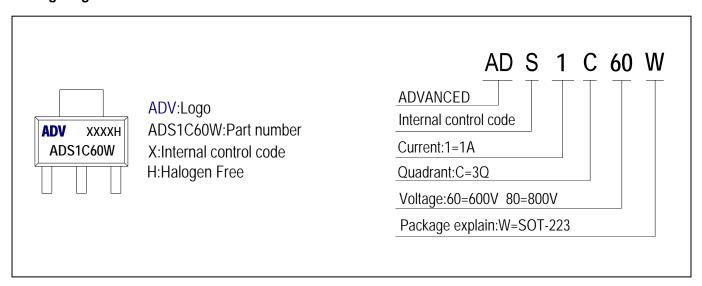


# PACKAGE MECHANICAL DATA SOT-223 Package Dimension



	Dimensions In		Dimensions In		
Symbol	Millimeters		Inches		
	Min	Max	Min	Max	
Α	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
С	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300 TYP		0.091 TYP		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	
b	0.660	0.820	0.026	0.032	
K	0.890	0.91	0.035	0.036	

### **Making Diagram**



### **Ordering information**

Part number	Package	Marking	Packing	Quantity
ADT1C60W	SOT-223	ADT1C60W	Embossed tape	2000pcs
ADT1C80W	SOT-223	ADT1C80W	Embossed tape	2000pcs



# ADS1C60W/80W

#### Notice

- 1. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any ADV products listed in this document, please confirm the latest product information with a ADV sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by ADV such as that disclosed through our website. (http://www.advsemi.com )
- 2. ADV has used reasonable care in compiling the information included in this document, but ADV assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
- 3. You should use the products described herein within the range specified by ADV, especially with respective the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. ADV shall have no liability for malfunctions or damages arising out of the use of ADV products beyond such specified ranges.
- 4. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. ADV makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or ADV products.
- 5. Although ADV endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a ADV product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by
- 6. This document is provided for reference purposes only so that ADV customers may select the appropriate ADV products for their use. ADV neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of ADV or any third party with respect to the information in this document.
- 7. ADV shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
- 8. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from ADV.

6 / 6 www.advsemi.com Feb,2013 -Rev.3.02